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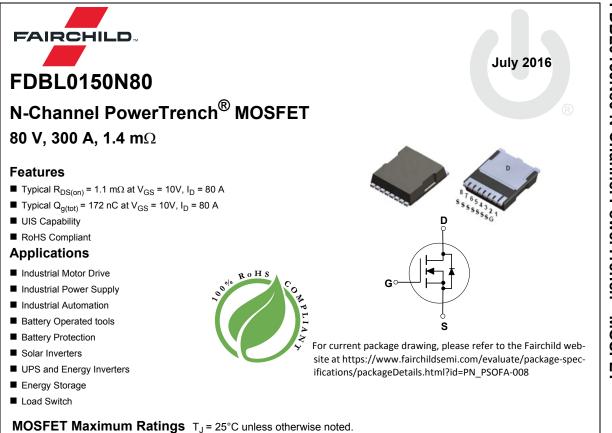


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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

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Symbol	Parameter		Ratings	Units	
V _{DSS}	Drain-to-Source Voltage		80	V	
V _{GS}	Gate-to-Source Voltage		±20	V	
1	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	300	Α	
I _D	Pulsed Drain Current	T _C = 25°C	See Figure 4		
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	820	mJ	
P _D	Power Dissipation		429	W	
	Derate Above 25°C		2.86	W/ ^o C	
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case		0.35	°C/W	
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	43	°C/W	

Notes:

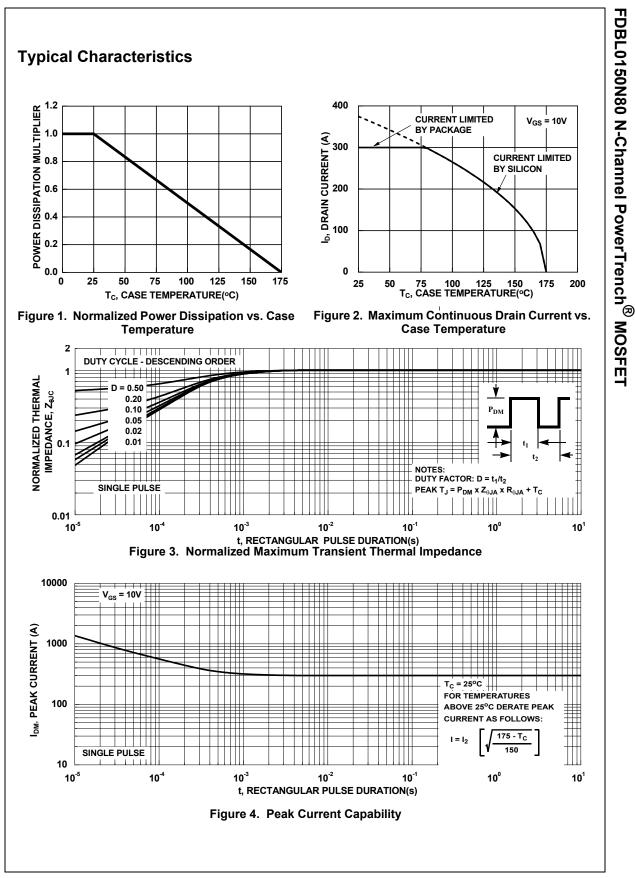
1: Current is limited by bondwire configuration.

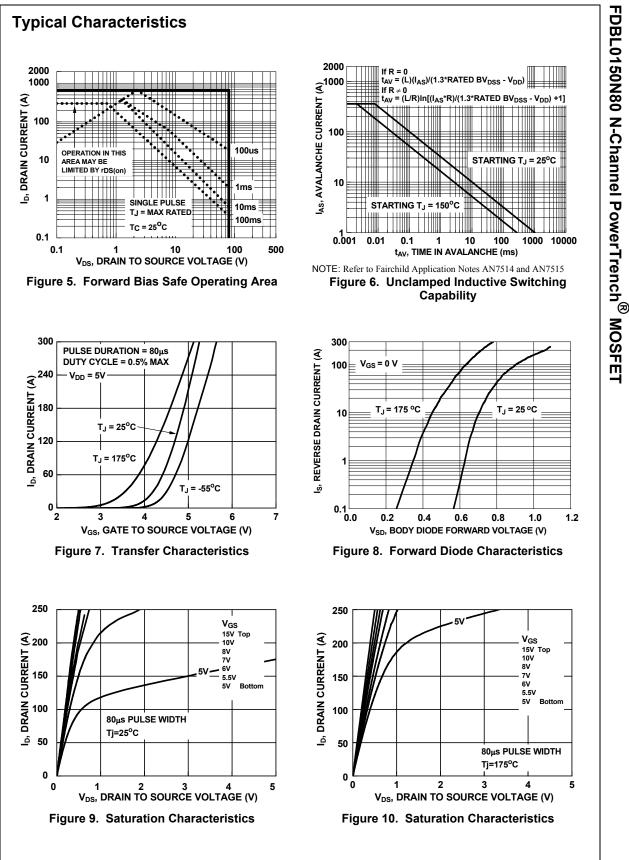
2: Starting T_J = 25°C, L = 0.4mH, I_{AS} = 64A, V_{DD} = 40V during inductor charging and V_{DD} = 0V during time in avalanche. 3: $R_{0,JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder moduling surface of the drain pins. $R_{\theta JC}$ is guaranteed by design, while $R_{\theta JA}$ is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

Package Marking and Ordering Information

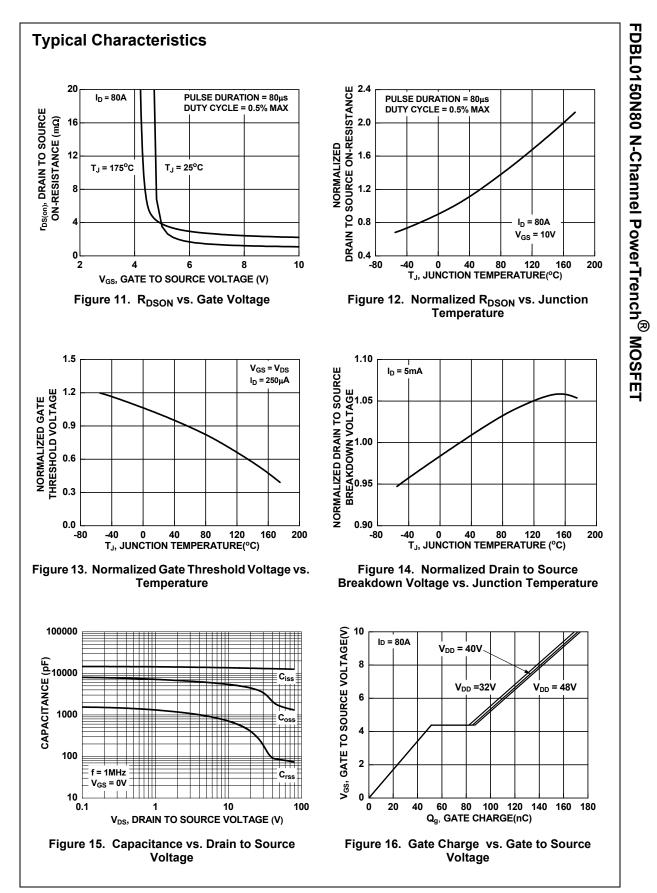
Device Marking	Device	Package			
FDBL0150N80	FDBL0150N80	MO-299A	-	-	-

Symbol	Parameter	Test Conditions		Тур.	Max.	Units
Off Cha	racteristics					
B _{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V		-	-	V
	Drain-to-Source Leakage Current	$V_{\rm DS}$ =80V, $T_{\rm J}$ =25°C	-	-	1	μA
I _{DSS}		$V_{GS} = 0V$ $T_J = 175^{\circ}C$ (Note 4)	-	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	V _{GS} = ±20V	-	-	±100	nA
On Cha	racteristics					
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250μA	2.0	3.0	4.0	V
	Drain to Source On Resistance	$I_D = 80A, T_J = 25^{\circ}C$	-	1.1	1.4	mΩ
R _{DS(on)}		V_{GS} = 10V T_{J} = 175°C (Note 4)	-	2.4	3.1	mΩ
Dynami C _{iss}	c Characteristics			12800	-	pF
C	Output Capacitance	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz		1925	_	pF
C _{oss}	Reverse Transfer Capacitance			1323	-	pF
C _{rss} P	Gate Resistance			3.0	4.6	ρι Ω
R _g	Total Gate Charge at 10V			172	188	nC
Q _{g(ToT)} Q _{g(th)}	Threshold Gate Charge	$V_{GS} = 0 \text{ to } 10V$ $V_{DD} = 64V$ $V_{GS} = 0 \text{ to } 2V$ $I_D = 80A$		23	27	nC
• • • •	Gate-to-Source Gate Charge	VGS 01021 ID - 00A		51	-	nC
Q _{gs} Q _{gd}	Gate-to-Drain "Miller" Charge		-	34	-	nC
Switchi	ng Characteristics			1		
t _{on}	Turn-On Time		-	-	128	ns
t _{d(on)}	Turn-On Delay		-	42	-	ns
t _r	Rise Time	$V_{DD} = 40V, I_D = 80A,$	-	73	-	ns
t _{d(off)}	Turn-Off Delay	V _{GS} = 10V, R _{GEN} = 6Ω	-	87	-	ns
t _f	Fall Time		-	48	-	ns
t _{off}	Turn-Off Time		-	-	193	ns
Drain-S	ource Diode Characteristics					
V_{SD}	Source-to-Drain Diode Voltage	I _{SD} =80A, V _{GS} = 0V	-	-	1.25	V
		I_{SD} = 40A, V_{GS} = 0V	-	-	1.2	V
t _{rr}	Reverse-Recovery Time	$I_{F} = 80A, dI_{SD}/dt = 100A/\mu s,$	-	117	136	ns
Q _{rr}	Reverse-Recovery Charge	$V_{DD}=64V$	-	205	269	nC

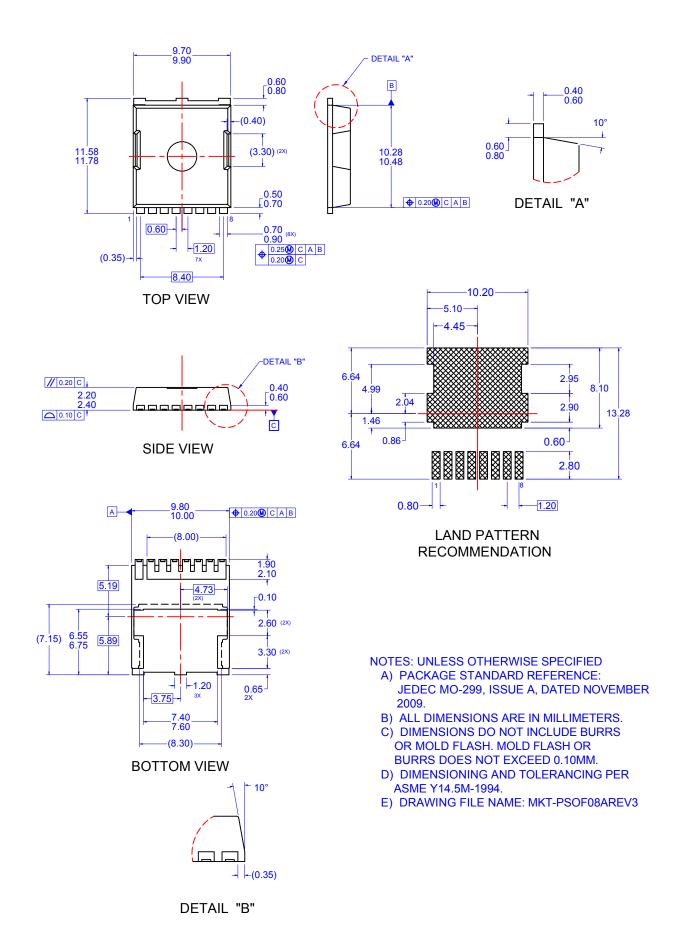




FDBL0150N80 Rev.1.2



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